

Electronic Supplementary Information (ESI)

Facile synthesis of a dopant-free hole transporting material with a phenothiazine core for planar perovskite solar cells

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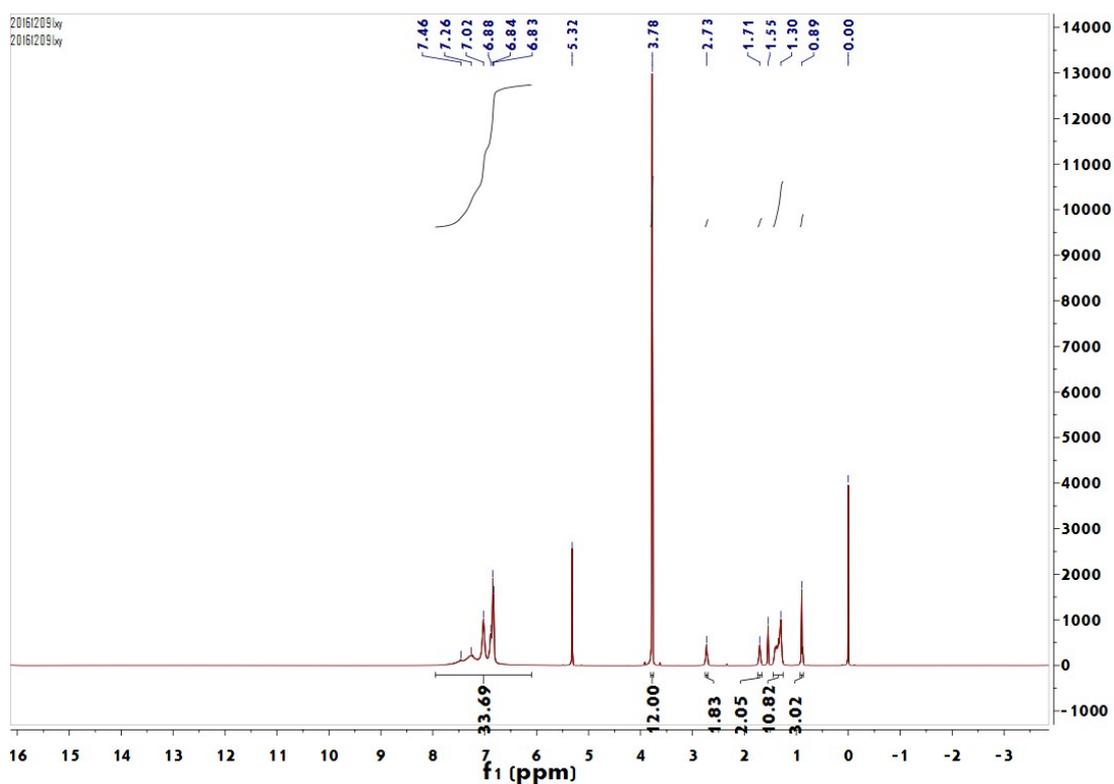


Fig. S1 ¹H NMR spectrum of PTZ-TPA in CD₂Cl₂.

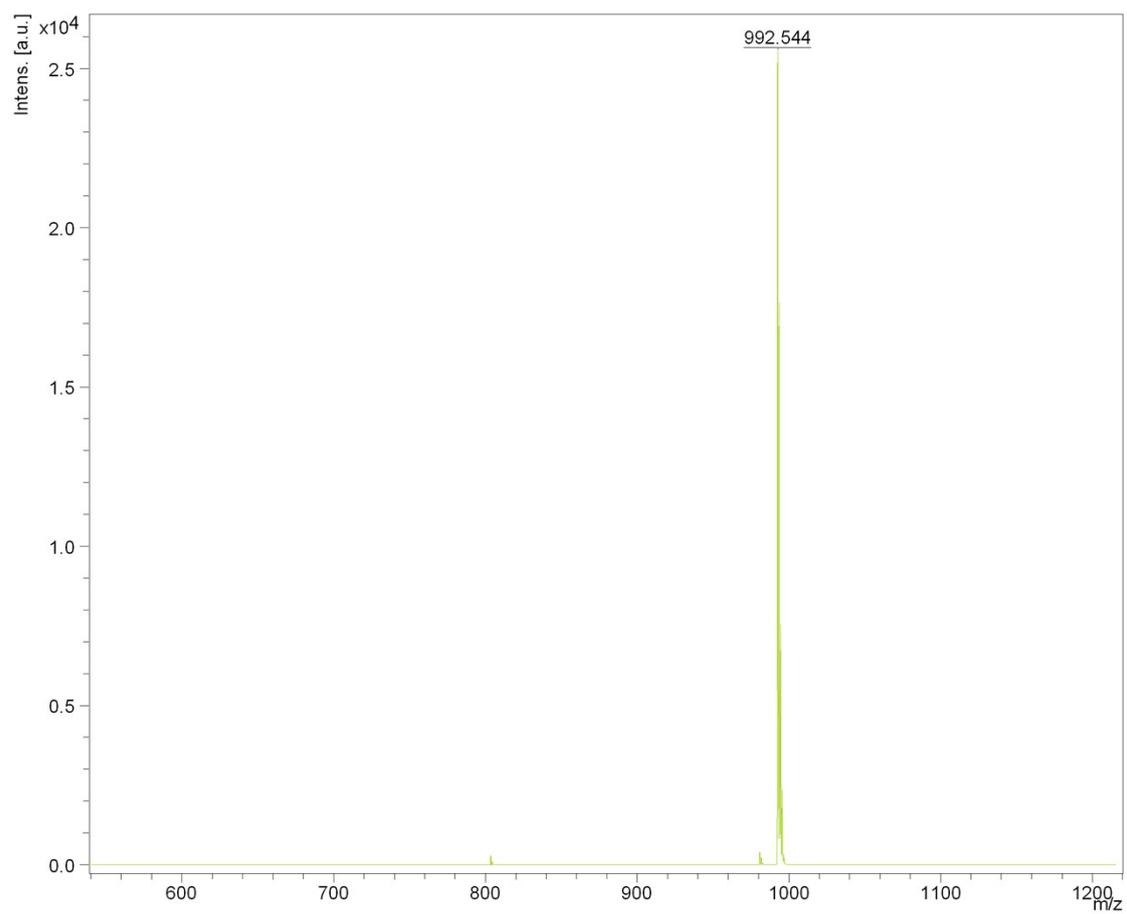


Fig. S2 MALDI-TOF mass spectra of PTZ-TPA

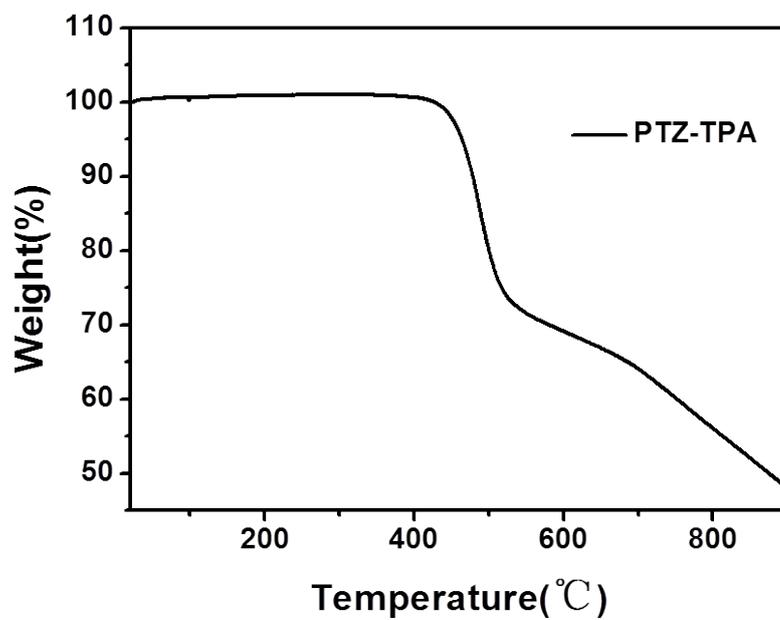


Fig. S3 Thermogravimetric analysis (TGA) curves of PTZ-TPA

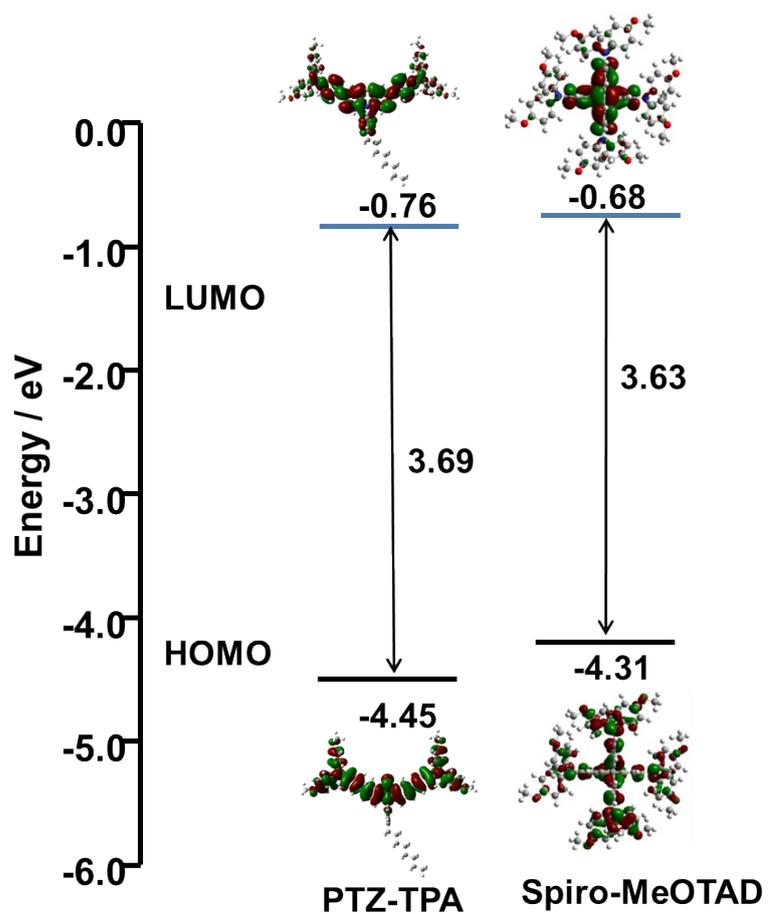


Fig. S4 Energy diagram showing the frontier molecular orbitals computed for PTZ-TPA and Spiro-MeOTAD at the B3LYP/6-31G* level.

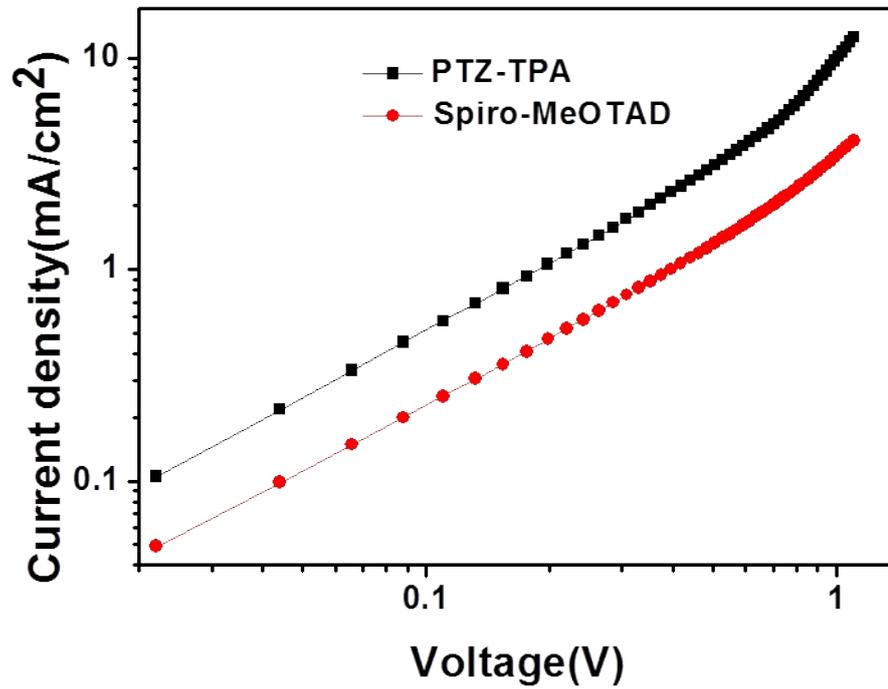


Fig. S5 J-V characteristics of space-charge-limited current of dopant-free HTMs.

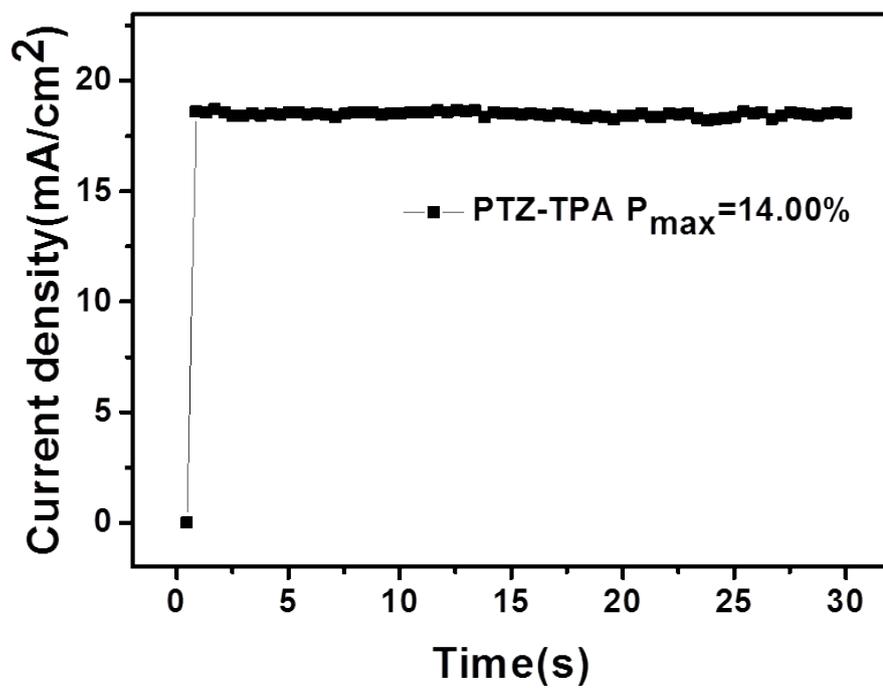


Fig. S6 Steady-state efficiency of PSC using PTZ-TPA

Table S1 Summary of the parameters from fitting to the TRPL measurement data.

Sample	A_1	τ_1 (ns)	A_2	τ_2 (ns)
PTZ-TPA	0.4317	6.743	0.4845	1.250
Spiro-MeOTAD	0.3718	4.905	0.7215	0.7655